TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS209C

CD74HC4067, CD74HCT4067

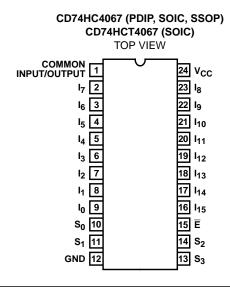
February 1998 - Revised July 2003

High-Speed CMOS Logic 16-Channel Analog Multiplexer/Demultiplexer

Features

- Wide Analog Input Voltage Range
- Low "ON" Resistance
- V_{CC} = 6V60Ω(Typ)
- Fast Switching and Propagation Speeds
- "Break-Before-Make" Switching. 6ns (Typ) at 4.5V
- Available in Both Narrow and Wide-Body Plastic Packages
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $\textbf{I}_{I} \leq 1 \mu \textbf{A}$ at $\textbf{V}_{OL},~\textbf{V}_{OH}$

Pinout



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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Description

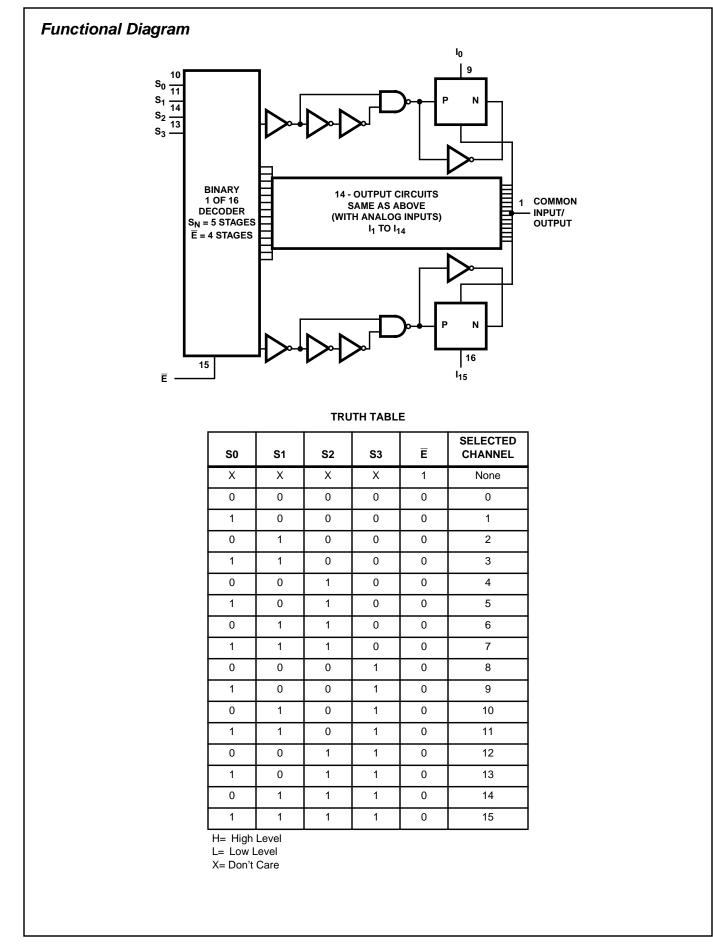
The CD74HC4067 and CD74HCT4067 devices are digitally controlled analog switches that utilize silicon-gate CMOS technology to achieve operating speeds similar to LSTTL, with the low power consumption of standard CMOS integrated circuits.

These analog multiplexers/demultiplexers control analog voltages that may vary across the voltage supply range. They are bidirectional switches thus allowing any analog input to be used as an output and vice-versa. The switches have low "on" resistance and low "off" leakages. In addition, these devices have an enable control which when high will disable all switches to their "off" state.

Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE				
CD74HC4067E	-55 to 125	24 Ld PDIP				
CD74HC4067M	-55 to 125	24 Ld SOIC				
CD74HC4067M96	-55 to 125	24 Ld SOIC				
CD74HC4067SM96	-55 to 125	24 Ld SSOP				
CD74HCT4067M	-55 to 125	24 Ld SOIC				

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.



Absolute Maximum Ratings

DC Supply Voltage, V _{CC} (Voltages Referenced to Ground)
DC Input Diode Current, I _{IK}
For $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$ ±20mA
DC Drain Current, I _O
For -0.5V < V _O < V _{CC} + 0.5V±25mA
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±20mA
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC} ±50mA

Operating Conditions

Temperature Range, T _A 55 ^o C to 125 ^o C
Supply Voltage Range, V _{CC}
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (^o C/W)
E (PDIP) Package, Note 1	67
M (SOIC) Package, Note 2	46
SM (SSOP) Package, Note 2	63
Maximum Junction Temperature (Plastic Package)	
Maximum Storage Temperature Range6	5 ^o C to 150 ^o C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 1. The package thermal impedance is calculated in accordance with JESD 51-3.
- 2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TEST CONDITIONS				25 ⁰ C			O 85°C	-55°C T	O 125 ⁰ C	
PARAMETER	SYMBOL	V _I (V)	V _{IS} (V)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-											
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
Maximum "ON"	R _{ON}	V _{CC} or GND	V _{CC} or GND	4.5	-	70	160	-	200	-	240	Ω
Resistance I _O = 1mA				6	-	60	140	-	175	-	210	Ω
0		V _{CC} to GND	V _{CC} to GND	4.5	-	90	180	-	225	-	270	Ω
				6	-	80	160	-	200	-	240	Ω
Maximum "ON"	ΔR_{ON}	-	-	4.5	-	10	-	-	-	-	-	Ω
Resistance Between Any Two Switches				6	-	8.5	-	-	-	-	-	Ω
Switch "Off" Leakage Current 16 Channels	I _{IZ}	$\overline{E} = V_{CC}$	V _{CC} or GND	6	-	-	±0.8	-	±8	-	±8	μA
Logic Input Leakage Current	lı	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA

DC Electrical Specifications (Continued)

			TEST CONDITIONS			25 ⁰ C		-40 ⁰ C 1	ГО 85 ⁰ С	-55°C T	O 125 ⁰ C	
PARAMETER	SYMBOL	V ₁ (V)	V _{IS} (V)	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current $I_O = 0mA$	ICC	V _{CC} or GND	-	6	-	-	8	-	80	-	160	μA
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	VIL	-	-	4.5	-	-	0.8	-	0.8	-	0.8	V
Maximum "ON" Resistance	R _{ON}	V _{CC} or GND	V _{CC} or GND	4.5	-	70	160	-	200	-	240	Ω
I _O = 1mA		V _{CC} to GND	V _{CC} to GND	4.5	-	90	180	-	225	-	270	Ω
Maximum "ON" Resistance Between Any Two Switches	∆R _{ON}	-	-	4.5	-	10	-	-	-	-	-	Ω
Switch "Off" Leakage Current 16 Channels	I _{IZ}	Ē = V _{CC}	V _{CC} or GND	6	-	-	±0.8	-	±8	-	±8	μΑ
Logic Input Leakage Current	lı	V _{CC} or GND (Note 3)	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	-	6	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 4)	V _{CC} -2.1	-	-	-	100	360	-	450	-	490	μΑ

NOTES:

3. Any voltage between $V_{\mbox{CC}}$ and GND.

4. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOAD
S ₀ - S ₃	0.5
Ē	0.3

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

Switching Specifications Input t_r, t_f = 6ns

	TEST	Vcc		25 ⁰ C		-40 ^o C T	О 85 ⁰ С	-55°C T	O 125 ⁰ C	
SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
		4.5	-	-	15	-	19	-	22	ns
		6	-	-	13	-	16	-	19	ns
	C _L = 15pF	5	-	6	-	-	-	-	-	ns
		t _{PLH} , t _{PHL} C _L = 50pF	SYMBOL CONDITIONS (V) t _{PLH} , t _{PHL} C _L = 50pF 2 4.5 6	SYMBOL CONDITIONS (V) MIN t _{PLH} , t _{PHL} C _L = 50pF 2 - 4.5 - 6 -	SYMBOL TEST CONDITIONS V _{CC} (V) MIN TYP t_{PLH}, t_{PHL} $C_L = 50pF$ 2 - - 4.5 - - 6 - -	SYMBOL CONDITIONS (V) MIN TYP MAX t_{PLH}, t_{PHL} $C_L = 50 pF$ 2 - - 75 4.5 - - 15 6 - 13	SYMBOL TEST CONDITIONS V _{CC} (V) MIN TYP MAX MIN t_{PLH}, t_{PHL} $C_L = 50pF$ 2 - - 75 - 4.5 - - 15 - 6 - - 13 -	SYMBOL TEST CONDITIONS V _{CC} (V) MIN TYP MAX MIN MAX t_{PLH}, t_{PHL} $C_L = 50pF$ 2 - - 75 - 95 4.5 - - 15 - 19 6 - - 13 - 16	SYMBOL TEST CONDITIONS VCC (V) MIN TYP MAX MIN MAX MIN t_{PLH}, t_{PHL} $C_L = 50pF$ 2 - - 75 - 95 - 4.5 - - 15 - 19 - 6 - - 13 - 16 -	SYMBOL TEST CONDITIONS V _{CC} (V) MIN TYP MAX MIN MAX MIN MAX t_{PLH}, t_{PHL} $C_L = 50pF$ 2 - - 75 - 95 - 110 4.5 - - 15 - 19 - 22 6 - - 13 - 16 - 19

		TEST	v _{cc}		25 ⁰ C		-40 ^о С Т	O 85°C	-55°C T	O 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	•CC (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Switch Turn On	t _{PZH} , t _{PZL}	C _L = 50pF	2	-	-	275	-	345	-	415	ns
Ē to Out			4.5	-	-	55	-	69	-	83	ns
			6	-	-	47	-	59	-	71	ns
		C _L = 15pF	5	-	23	-	-	-	-	-	ns
Switch Turn On	t _{PZH} , t _{PZL}	C _L = 50pF	2	-	-	300	-	375	-	450	ns
Sn to Out			4.5	-	-	60	-	75	-	90	ns
			6	-	-	51	-	64	-	76	ns
		C _L = 15pF	5	-	25	-	-	-	-	-	ns
Switch Turn Off	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	-	275	-	345	-	415	ns
Ē to Out			4.5	-	-	55	-	69	-	83	ns
			6	-	-	47	-	59	-	71	ns
		C _L = 15pF	5	-	23	-	-	-	-	-	ns
Switch Turn Off	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	-	290	-	365	-	435	ns
Sn to Out			4.5	-	-	58	-	73	-	87	ns
			6	-	-	49	-	62	-	74	ns
		C _L = 50pF	5	-	21	-	-	-	-	-	ns
Input (Control) Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 5, 6)	C _{PD}	-	5	-	93	-	-	-	-	-	pF
HCT TYPES		•		•					•		
Propagation Delay Time	t _{PLH} , t _{PHL}	$C_L = 50 pF$	4.5	-	-	15	-	19	-	22	ns
Switch In to Out		C _L = 15pF	5	-	6	-	-	-	-	-	ns
Switch Turn On	t _{PZH} , t _{PZL}	C _L = 50pF	4.5	-	-	60	-	75	-	 MAX 415 83 71 - 450 90 76 77 415 83 71 - 435 87 74 - 10 - 22 	ns
E to Out		C _L = 15pF	5	-	25	-	-	-	-	-	ns
Switch Turn On	t _{PZH} , t _{PZL}	C _L = 50pF	4.5	-	-	60	-	75	-	90	ns
Sn to Out		C _L = 15pF	5	-	25	-	-	-	-	-	ns
Switch Turn Off	t _{PHZ} , t _{PLZ}	C _L = 50pF	4.5	-	-	55	-	69	-	83	ns
Ē to Out		C _L = 15pF	5	-	23	-	-	-	-	-	ns
Switch Turn Off	t _{PHZ} , t _{PLZ}	C _L = 50pF	4.5	-	-	58	-	73	-	87	ns
Sn to Out		C _L = 15pF	5	-	21	-	-	-	-	-	ns
Input (Control) Capacitance	CI	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 5, 6)	C _{PD}	-	5	-	96	-	-	-	-	-	pF

_ . ..

NOTES:

C_{PD} is used to determine the dynamic power consumption, per package.
 P_D = C_{PD} V_{CC}² f_i + Σ (C_L + C_S) V_{CC}² f_o where f_i = input frequency, f_o = output frequency, C_L = output load capacitance, C_S = switch capacitance, V_{CC} = supply voltage.

Analog Channel Specifications T_A = 25°C

PARAMETER	TEST CONDITIONS	V _{CC} (V)	НС/НСТ	UNITS
Switch Frequency Response Bandwidth at -3dB (Figure 2)	Figure 4, Notes 7, 8	4.5	89	MHz
Sine Wave Distortion	Figure 5	4.5	0.051	%
Feedthrough Noise E to Switch	Figure 6, Notes 8, 9	4.5	ТВЕ	mV
Feedthrough Noise S to Switch			ТВЕ	mV
Switch "OFF" Signal Feedthrough (Figure 3)	Figure 7	4.5	-75	dB
Switch Input Capacitance, CS		-	5	pF
Common Capacitance, C _{COM}		-	50	pF

NOTES:

7. Adjust input level for 0dBm at output, f = 1MHz.

- 8. V_{IS} is centered at $V_{CC}/2$.
- 9. Adjust input for 0dBm at $\ensuremath{\mathsf{V}_{\mathsf{IS}}}$.

Typical Performance Curves

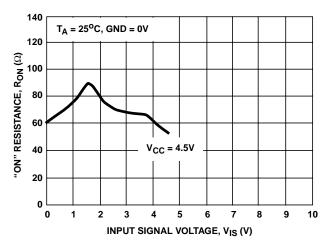


FIGURE 1. TYPICAL "ON" RESISTANCE vs INPUT SIGNAL VOLTAGE

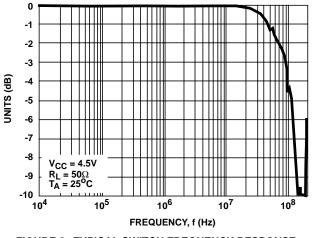


FIGURE 2. TYPICAL SWITCH FREQUENCY RESPONSE

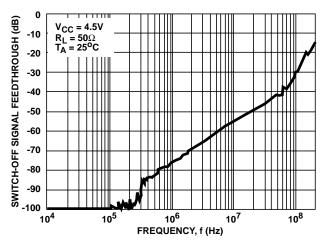


FIGURE 3. TYPICAL SWITCH-OFF SIGNAL FEEDTHROUGH vs FREQUENCY

Analog Test Circuits

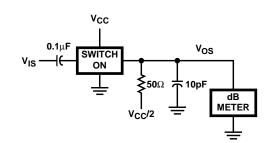


FIGURE 4. FREQUENCY RESPONSE TEST CIRCUIT

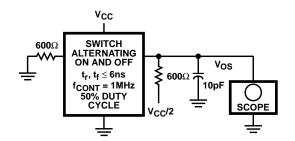


FIGURE 6. CONTROL-TO-SWITCH FEEDTHROUGH NOISE TEST CIRCUIT

Test Circuits and Waveforms

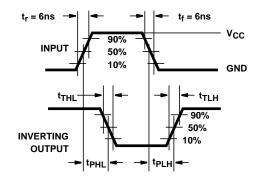


FIGURE 8. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

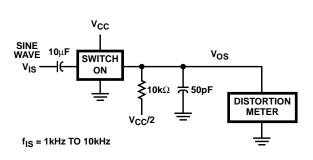
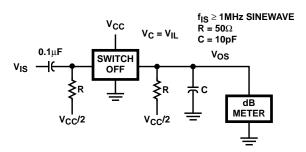


FIGURE 5. SINE WAVE DISTORTION TEST CIRCUIT





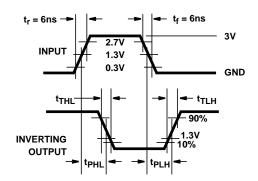


FIGURE 9. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	-	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD74HC4067M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4067M	Samples
CD74HC4067M96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-55 to 125	HC4067M	Samples
CD74HC4067M96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4067M	Samples
CD74HC4067M96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4067M	Samples
CD74HC4067MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4067M	Samples
CD74HC4067SM96	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HP4067	Samples
CD74HC4067SM96E4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HP4067	Samples
CD74HC4067SM96G4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HP4067	Samples
CD74HCT4067M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4067M	Samples
CD74HCT4067ME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4067M	Samples
CD74HCT4067MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4067M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS**: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.



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⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD74HCT4067 :

Automotive: CD74HCT4067-Q1

NOTE: Qualified Version Definitions:

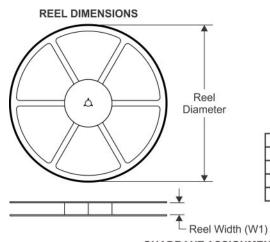
• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

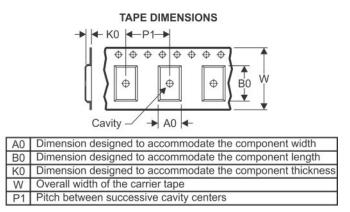
PACKAGE MATERIALS INFORMATION

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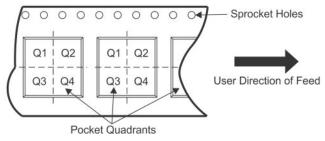
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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4067M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HC4067M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HC4067M96G4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HC4067SM96	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Feb-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4067M96	SOIC	DW	24	2000	364.0	361.0	36.0
CD74HC4067M96	SOIC	DW	24	2000	350.0	350.0	43.0
CD74HC4067M96G4	SOIC	DW	24	2000	350.0	350.0	43.0
CD74HC4067SM96	SSOP	DB	24	2000	367.0	367.0	38.0

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



LAND PATTERN DATA



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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